Notice of References Cited Application/Control No. 10/691,540 Applicant(s)/Patent Under Reexamination MOTOKI ET AL. Examiner Matthew J. Song 1722 Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	Α	US-		·	
	В	US-			
	С	US-			
	D	US-			
	ш	US-			
	ш	US-			
	G	US-			
	Ŧ	US-			
	1	US-		12 11 11 11 11 11	
	J	US-			
	Κ	US-			
1.17	L	US-			
	М	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N				,	
	0					
	Р	·				
123	α					
	·R					
	S					
	Т					

NON-PATENT DOCUMENTS

	NON-PAIENT DOCUMENTS						
*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)					
	U	Nam et al. "Growth of GaN and Al0.2Ga0.8N on Patterned Substrates via Organometallic Vapor Phase Epitaxy"Jpn. j. Appl. Phys. Vol 36 (May 1, 1997), Pt. 2, No. 5A, pg L532-L535.					
	V						
	w						
	x						

^{*}A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.